

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage		Vcc	-50	V
Input Voltage	DDA124EH DDA144EH DDA143EH DDA114YH DDA114YH DDA123JH DDA114EH DDA114TH DDA114TH	V <sub>IN</sub>	+10 to -40 +10 to -40 +10 to -30 +6 to -40 +5 to -12 +10 to -40 +5V Max +5V Max	V
Output Current	DDA124EH DDA144EH DDA143EH DDA114YH DDA123JH DDA123JH DDA114EH DDA143TH DDA114TH	ю	-30 -30 -100 -70 -100 -50 -100 -100	mA
Output Current	All	I <sub>C</sub> (Max)	-100	mA
Power Dissipation		PD	150	mW
Thermal Resistance, Junction to Ambient Air	(Note 5)	R <sub>0JA</sub>	833	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Note: 5. Mounted on FR4 Board with recommended pad layout at http://www.diodes.com/package-outlines.html.



# Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified.)

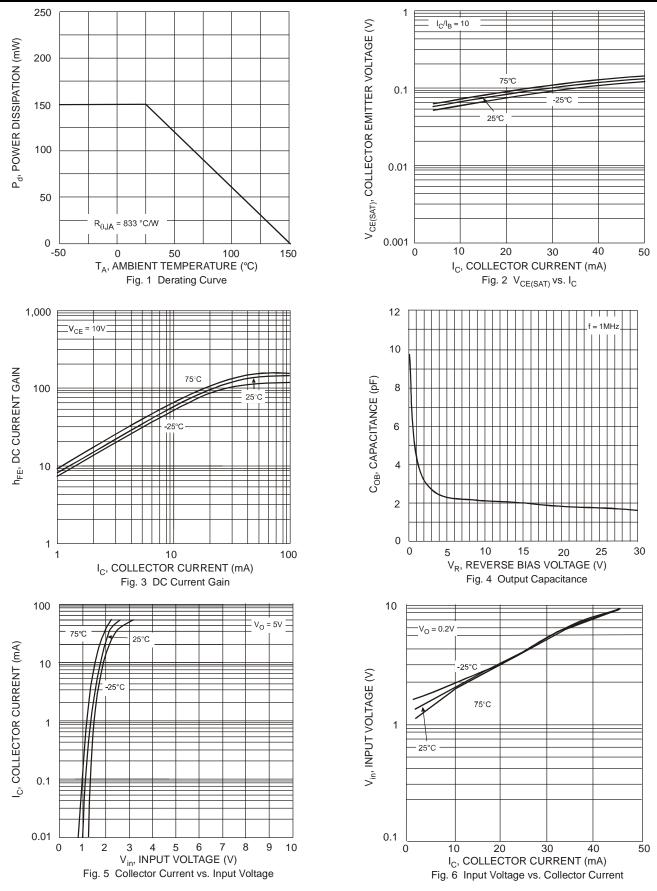
Characteristic (DDA143TH & DDA114TH only)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВV <sub>сво</sub>	-50	_	_	V	I <sub>C</sub> = -50μΑ
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-50		_	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5		_	V	Ι <sub>Ε</sub> = -50μΑ
Collector Cut-Off Current	I <sub>СВО</sub>			-0.5	μA	V <sub>CB</sub> = -50V
Emitter Cut-Off Current	I <sub>EBO</sub>			-0.5	μA	$V_{EB} = -4V$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>			-0.3	V	I <sub>C</sub> /I <sub>B</sub> = -2.5mA / -0.25mA DDA143TH I <sub>C</sub> /I <sub>B</sub> = -1mA / -0.1mA DDA114TH
DC Current Transfer Ratio	h <sub>FE</sub>	100	250	600		$I_C = -1mA$ , $V_{CE} = -5V$
Gain-Bandwidth Product*	f <sub>T</sub>		250	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz

Characte	eristic	Symbol	Min	Тур	Мах	Unit	Test Condition
	DDA124EH DDA144EH DDA143EH DDA114YH DDA123JH DDA114EH	V <sub>L(OFF)</sub>	-0.5 -0.5 -0.3 -0.3 -0.5 -0.5	-1.1 -1.1 -1.1 — — -1.1		V	V <sub>CC</sub> = -5V, I <sub>O</sub> = -100µA
Input Voltage	DDA124EH DDA144EH DDA143EH DDA114YH DDA123JH DDA114EH	V <sub>L(ON)</sub>		-1.9 -1.9 -1.9 -1.9 -1.9	-3.0 -3.0 -1.4 -1.1 -3.0		$ \begin{array}{l} V_{O}=-0.3V, \ I_{O}=-5mA \\ V_{O}=-0.3V, \ I_{O}=-2mA \\ V_{O}=-0.3V, \ I_{O}=-20mA \\ V_{O}=-0.3V, \ I_{O}=-1mA \\ V_{O}=-0.3V, \ I_{O}=-5mA \\ V_{O}=-0.3V, \ I_{O}=-10mA \end{array} $
Output Voltage	DDA124EH DDA144EH DDA143EH DDA114YH DDA123JH DDA114EH	V <sub>O(ON)</sub>	_	-0.1	-0.3	V	I <sub>O</sub> /I <sub>L</sub> = -10mA / -0.5mA I <sub>O</sub> /I <sub>L</sub> = -10mA / -0.5mA I <sub>O</sub> /I <sub>L</sub> = -10mA / -0.5mA I <sub>O</sub> /I <sub>L</sub> = -5mA / -0.25mA I <sub>O</sub> /I <sub>L</sub> = -5mA / -0.25mA I <sub>O</sub> /I <sub>L</sub> = -10mA / -0.5mA
Input Current	DDA124EH DDA144EH DDA143EH DDA114YH DDA123JH DDA114EH	١L	_	_	-0.36 -0.18 -1.8 -0.88 -3.6 -0.88	mA	V <sub>I</sub> = -5V
Output Current		I <sub>O(OFF)</sub>	—	—	-0.5	μA	$V_{CC} = -50V, V_{I} = -0V$
DC Current Gain	DDA124EH DDA144EH DDA143EH DDA114YH DDA123JH DDA123JH DDA114EH	GL	56 68 20 68 80 30			_	$V_{O} = -5V, I_{O} = -5mA$ $V_{O} = -5V, I_{O} = -5mA$ $V_{O} = -5V, I_{O} = -10mA$ $V_{O} = -5V, I_{O} = -10mA$ $V_{O} = -5V, I_{O} = -10mA$ $V_{O} = -5V, I_{O} = -5mA$
Gain-Bandwidth Product*		fT	_	250	_	MHz	$V_{CE} = -10V, I_E = -5mA, f = 100MHz$

\* Transistor - For Reference Only



## **Typical Curves - DDA143EH**

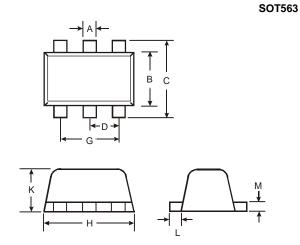


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## **Package Outline Dimensions**

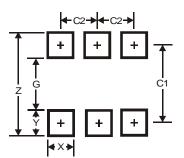
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563					
Dim	Min	Max	Тур		
Α	0.15	0.30	0.20		
в	1.10	1.25	1.20		
с	1.55	1.70	1.60		
D	-	-	0.50		
G	0.90	1.10	1.00		
Н	1.50	1.70	1.60		
Κ	0.55	0.60	0.60		
L	0.10	0.30	0.20		
Μ	0.10	0.18	0.11		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563

Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5



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